

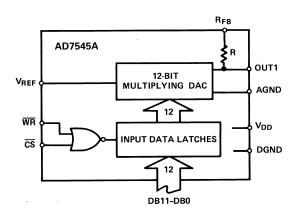
CMOS 12-Bit Buffered Multiplying DAC

AD7545A

FEATURES

Improved Version of AD7545 Fast Interface Timing All Grades 12-Bit Accurate 20-Lead DIP and Surface Mount Packages Low Cost

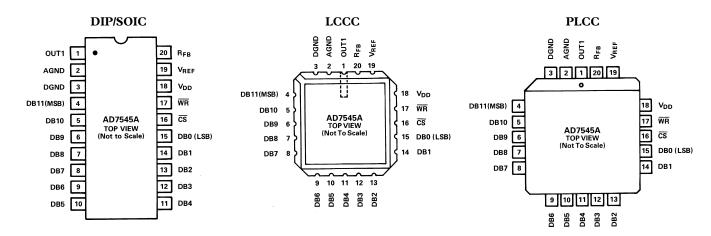




GENERAL DESCRIPTION

The AD7545A, a 12-bit CMOS multiplying DAC with internal data latches, is an improved version of the industry standard AD7545. This new design features a \overline{WR} pulse width of 100 ns, which allows interfacing to a much wider range of fast 8-bit and 16-bit microprocessors. It is loaded by a single 12-bit-wide word under the control of the \overline{CS} and \overline{WR} inputs; tying these control inputs low makes the input latches transparent, allowing unbuffered operation of the DAC.

PIN CONFIGURATIONS



REV. C

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$\label{eq:AD7545A} AD7545A - SPECIFICATIONS \quad (v_{\text{REF}} = \pm 10 \text{ V}, v_{\text{OUT1}} = 0 \text{ V}, \text{AGND} = \text{DGND} \text{ unless otherwise noted})$

| | | | = +5 V mits | V _{DD} = +1: Limits | 5 V | | |
|---|------------|------------------------|---------------------------|---------------------------------|---------------------------|-------------|--|
| Parameter | Version | T _A = + 25° | C $T_{MIN} - T_{MAX}^{1}$ | $T_A = +25^{\circ}C$ | T_{MIN} - T_{MAX}^{1} | Units | Test Conditions/Comments |
| STATIC PERFORMANCE | | | | | | | |
| Resolution | All | 12 | 12 | 12 | 12 | Bits | |
| Relative Accuracy | K, B, T | $\pm 1/2$ | $\pm 1/2$ | $\pm 1/2$ | $\pm 1/2$ | LSB max | |
| J. | L, C, U | $\pm 1/2$ | $\pm 1/2$ | ±1/2 | $\pm 1/2$ | LSB max | Endpoint Measurement |
| Differential Nonlinearity | All | ±1 | ±1 | ±1 | ±1 | LSB max | All Grades Guaranteed 12-Bit |
| 2 merendur 1 (ommenney | | | | | | 202 | Monotonic Over Temperature |
| Gain Error | K, B, T | ±3 | ± 4 | ±3 | ± 4 | LSB max | Measured Using Internal R _{FB} . |
| | L, C, U | ±1 | ±2 | ±1 | ±2 | LSB max | DAC Register Loaded with All 1s. |
| Gain Temperature Coefficient ² | All | ±5 | ±2 ±5 | ±5 | ±2 ±5 | ppm/°C max | Diffe Register Loaded with fin 13. |
| $\Delta Gain/\Delta Temperature$ | All | ±2 | ±2 | ±2 | ±2 | ppm/°C typ | |
| DC Supply Rejection ² | | 12 | 12 | 14 | 12 | ppin/ C typ | |
| | A 11 | 0.000 | 0.004 | 0.000 | 0.004 | 0/ 0/ | 137 1 50/ |
| $\Delta Gain/\Delta V_{DD}$ | All | 0.002 | 0.004 | 0.002 | 0.004 | % per % max | $\Delta V_{DD} = \pm 5\%$ |
| Output Leakage Current at OUT1 | K, L | 10 | 50 | 10 | 50 | nA max | DB0–DB11 = 0 V; \overline{WR} , \overline{CS} = 0 V |
| | B, C | 10 | 50 | 10 | 50 | nA max | |
| | T, U | 10 | 200 | 10 | 200 | nA max | |
| DYNAMIC PERFORMANCE | | | | | | | |
| Current Settling Time ² | All | 1 | 1 | 1 | 1 | µs max | To $1/2$ LSB. OUT1 Load = 100 Ω , |
| 0 | | | | | | | C_{EXT} = 13 pF. DAC Output Measured |
| | | | | | | | from Falling Edge of \overline{WR} , $\overline{CS} = 0$ V. |
| Propagation Delay ² (from Digital | | | | | | | |
| Input Change to 90% | | | | | | | |
| of Final Analog Output) | All | 200 | | 150 | | ns max | OUT1 Load = 100 Ω , C _{EXT} = 13 pF ³ |
| Digital-to-Analog Glitch Impulse | All | 5 | _ | 5 | _ | | $V_{\text{REF}} = \text{AGND. OUT1 Load} = 100 \Omega,$ |
| Digital-to-Allalog Gilten Impulse | | 5 | - | | - | nV sec typ | Alternately Loaded with All 0s and 1s. |
| AC Feedthrough ^{2, 4} | | | | | | | Alternately Loaded with All 08 and 18. |
| At OUT1 | All | 5 | 5 | 5 | 5 | mV n_n twn | $V_{REF} = \pm 10 \text{ V}, 10 \text{ kHz}$ Sine Wave |
| | 7111 | 5 | 5 | , | 5 | mV p-p typ | $v_{\rm REF} = \pm 10$ V, 10 KHz Sine wave |
| REFERENCE INPUT | | | | | | | |
| Input Resistance | All | 10 | 10 | 10 | 10 | kΩ min | Input Resistance TC = $-300 \text{ ppm/}^{\circ}\text{C ty}$ |
| (Pin 19 to GND) | | 20 | 20 | 20 | 20 | kΩ max | Typical Input Resistance = $15 \text{ k}\Omega$ |
| ANALOG OUTPUTS | | | | | | | |
| Output Capacitance ² | | | | | | | |
| C _{OUT1} | All | 70 | 70 | 70 | 70 | pF max | DB0–DB11 = 0 V, \overline{WR} , \overline{CS} = 0 V |
| C _{OUT1} | | 150 | 150 | 150 | 150 | pF max | DB0–DB11 = V_{DD} , \overline{WR} , \overline{CS} = 0 V |
| DIGITAL INPUTS | | | | | | - | |
| Input High Voltage | | | | | | | |
| V _{IH} | All | 2.4 | 2.4 | 13.5 | 13.5 | V min | |
| | 7311 | 2.4 | 2.4 | 15.5 | 15.5 | V IIIII | |
| Input Low Voltage | A 11 | 0.8 | 0.9 | 1.5 | 1.5 | Vmou | |
| V _{IL} | All | 0.8 | 0.8 | 1.5 | 1.5 | V max | |
| Input Current ⁵ | A 11 | . 1 | 1.10 | | 1.10 | | $\mathbf{V} = 0 + \mathbf{v} \mathbf{V}$ |
| I _{IN} Input Capacitance ² | All | ±1 | ± 10 | ±1 | ± 10 | µA max | $V_{IN} = 0$ or V_{DD} |
| | A 11 | 0 | 0 | 0 | 0 | | |
| $DB0-DB11, \overline{WR}, \overline{CS}$ | All | 8 | 8 | 8 | 8 | pF max | |
| SWITCHING CHARACTERISTICS ² | | | | | | | |
| Chip Select to Write Setup Time | K, B, L, C | 100 | 130 | 75 | 85 | ns min | See Timing Diagram |
| t _{CS} | T, U | 100 | 170 | 75 | 95 | ns min | |
| Chip Select to Write Hold Time | | | | | | | |
| t _{CH} | All | 0 | 0 | 0 | 0 | ns min | |
| Write Pulse Width | K, B, L, C | 100 | 130 | 75 | 85 | ns min | $t_{CS} \ge t_{WR}, T_{CH} \ge 0$ |
| t _{wR} | T, U | 100 | 170 | 75 | 95 | ns min | |
| Data Setup Time | | | | | | | |
| t _{DS} | All | 100 | 150 | 60 | 80 | ns min | |
| Data Hold Time | | | | | | | |
| t _{DH} | All | 5 | 5 | 5 | 5 | ns min | |
| | | | - | 1 | | | |
| POWER SUPPLY | A 11 | _ | 5 | 15 | 15 | v | + 5% For Specified Derformer |
| V _{DD} | All | 5 | 5 | 15 | 15 | V | $\pm 5\%$ For Specified Performance |
| I _{DD} | All | 2 | 2 | 2 | 2 | mA max | All Digital Inputs V_{IL} or V_{IH} |
| | | 100 | 100 | 100 | 100 | µA max | All Digital Inputs 0 V or V _{DD} |
| | 1 | 10 | 10 | 10 | 10 | µA typ | All Digital Inputs 0 V or V _{DD} |

NOTES

¹Temperature range as follows: K, L Versions = 0°C to +70°C; B, C Versions = -25°C to +85°C; T, U Versions = -55°C to +125°C.

²Sample tested to ensure compliance.

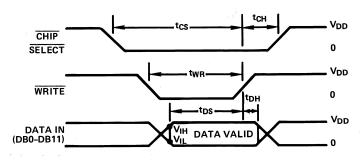
 ${}^{3}\text{DB0-DB11} = 0 \text{ V to } \text{V}_{\text{DD}} \text{ or } \text{V}_{\text{DD}} \text{ to } 0 \text{ V}.$

⁴Feedthrough can be further reduced by connecting the metal lid on the ceramic package to DGND.

⁶Logic inputs are MOS gates. Typical input current (+25°C) is less than 1 nA.

Specifications subject to change without notice.

WRITE CYCLE TIMING DIAGRAM



ABSOLUTE MAXIMUM RATINGS*

 $(T_A = + 25^{\circ}C \text{ unless otherwise noted})$

| V _{DD} to DGND |
|---|
| Digital Input Voltage to DGND0.3 V, V _{DD} +0.3 V |
| V_{RFB} , V_{REF} to DGND ±25 V |
| V_{PIN1} to DGND0.3 V, V_{DD} +0.3 V |
| AGND to DGND $\dots \dots \dots$ |
| Power Dissipation (Any Package) to 75°C 450 mW |
| Derates above 75°C by $\dots \dots \dots$ |

MODE SELECTION

WRITE MODE: CS and WR low, DAC responds to data bus (DB0-DB11) inputs.

 $\begin{array}{l} \text{HOLD MODE:} \\ \text{Either } \overline{\text{CS}} \text{ or } \overline{\text{WR}} \text{ high, data bus} \\ \text{(DB0-DB11) is locked out; DAC} \\ \underline{\text{holds } \text{last}} \text{ data present when} \\ \overline{\text{WR}} \text{ or } \overline{\text{CS}} \text{ assumed high state.} \end{array}$

NOTES: $V_{DD} = +5V$; $t_r = t_f = 20ns$ $V_{DD} = +15V$; $t_r = t_f = 40ns$ All input signal rise and fall times measured from 10% to 90% of V_{DD} . Timing measurement reference level is $\frac{V_{IH} + V_{IL}}{2}$.

Operating Temperature Range

| Commercial (KN, LN, KP, LP) Grades \dots 0°C to +70°C |
|---|
| Industrial (BQ, CQ, BE, CE) Grades \dots -25°C to +85°C |
| Extended (TQ, UQ, TE, UE) Grades55°C to +125°C |
| Storage Temperature |
| Lead Temperature (Soldering, 10 secs) +300°C |

*Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

CAUTION_

ESD (electrostatic discharge) sensitive device. The digital control inputs are diode protected; however, permanent damage may occur on unconnected devices subject to high energy electrostatic fields. Unused devices must be stored in conductive foam or shunts. The protective foam should be discharged to the destination socket before devices are removed.



ORDERING GUIDE

| Model ¹ | Temperature Range | Relative Accuracy T _{MIN} -T _{MAX} | Gain Error T _{MIN} -T _{MAX} | Package Options ² |
|--------------------|----------------------|--|---|---------------------------------|
| AD7545AKN | 0°C to +70°C | $\pm 1/2$ | ± 4 | N-20 |
| AD7545ALN | 0°C to +70°C | $\pm 1/2$ | ±2 | N-20 |
| AD7545AKR | 0°C to +70°C | $\pm 1/2$ | ± 4 | R-20 |
| AD7545AKP | 0°C to +70°C | $\pm 1/2$ | ± 4 | P-20A |
| AD7545ALP | 0°C to +70°C | $\pm 1/2$ | ± 2 | P-20A |
| AD7545ABQ | –25°C to +85°C | $\pm 1/2$ | ± 4 | Q-20 |
| AD7545ACQ | –25°C to +85°C | $\pm 1/2$ | ± 2 | Q-20 |
| AD7545ABE | -25°C to +85°C | $\pm 1/2$ | ± 4 | E-20A |
| AD7545ACE | –25°C to +85°C | $\pm 1/2$ | ± 2 | E-20A |
| AD7545ATQ | –55°C to +125°C | $\pm 1/2$ | ± 4 | Q-20 |
| AD7545AUQ | –55°C to +125°C | $\pm 1/2$ | ± 2 | Q-20 |
| AD7545ATE | –55°C to +125°C | $\pm 1/2$ | ± 4 | E-20A |
| AD7545AUE | –55°C to +125°C | $\pm 1/2$ | ±2 | E-20A |

NOTES

¹To order MIL-STD-883, Class B process parts, add /883B to part number. Contact local sales office for military data sheet.

²E = Leadless Ceramic Chip Carrier (LCCC); N = Plastic DIP; P = Plastic Leaded Chip Carrier (PLCC); Q = Cerdip; R = Small Outline IC.

CIRCUIT INFORMATION-D/A CONVERTER SECTION

Figure 1 shows a simplified circuit of the D/A converter section of the AD7545A, and Figure 2 gives an approximate equivalent circuit. Note that the ladder termination resistor is connected to AGND. R is typically 15 k Ω .

The binary weighted currents are switched between the OUT1 bus line and AGND by N-channel switches, thus maintaining a constant current in each ladder leg independent of the switch state.

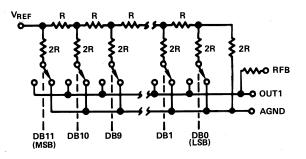


Figure 1. Simplified D/A Circuit of AD7545A

The capacitance at the OUT1 bus line, C_{OUT1} , is codedependent and varies from 70 pF (all switches to AGND) to 150 pF (all switches to OUT1).

One of the current switches is shown in Figure 2. The input resistance at V_{REF} (Figure 1) is always equal to R. Since R_{IN} at the V_{REF} pin is constant, the reference terminal can be driven by a reference voltage or a reference current, ac or dc, of positive or negative polarity. (If a current source is used, a low temperature coefficient external R_{FB} is recommended to define scale factor.)

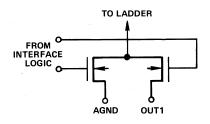


Figure 2. N-Channel Current Steering Switch

CIRCUIT INFORMATION—DIGITAL SECTION

Figure 3 shows the digital structure for one bit.

The digital signals CONTROL and $\overline{\text{CONTROL}}$ are generated from $\overline{\text{CS}}$ and $\overline{\text{WR}}$.

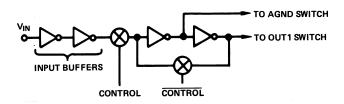


Figure 3. Digital Input Structure

The input buffers are simple CMOS inverters designed such that when the AD7545A is operated with V_{DD} = 5 V, the buffers convert TTL input levels (2.4 V and 0.8 V) into CMOS logic levels. When V_{IN} is in the region of 2.0 volts to 3.5 volts, the

input buffers operate in their linear region and draw current from the power supply. To minimize power supply currents it is recommended that the digital input voltages be as close to the supply rails (V_{DD} and DGND) as is practically possible.

The AD7545A may be operated with any supply voltage in the range $5 \le V_{DD} \le 15$ volts. With $V_{DD} = +15$ V the input logic levels are CMOS compatible only, i.e., 1.5 V and 13.5 V.

BASIC APPLICATIONS

Figures 4 and 5 show simple unipolar and bipolar circuits using the AD7545A. Resistor R1 is used to trim for full scale. The L, C, U grades have a guaranteed maximum gain error of ± 1 LSB at +25°C, and in many applications it should be possible to dispense with gain trim resistors altogether. Capacitor C1 provides phase compensation and helps prevent overshoot and ringing when using high speed op amps. Note that all the circuits of Figures 4, 5 and 6 have constant input impedance at the V_{REF} terminal.

The circuit of Figure 4 can either be used as a fixed reference D/A converter so that it provides an analog output voltage in the range 0 to $-V_{IN}$ (note the inversion introduced by the op amp) or V_{IN} can be an ac signal in which case the circuit behaves as an attenuator (2-Quadrant Multiplier). V_{IN} can be any voltage in the range $-20 \leq V_{IN} \leq +20$ volts (provided the op amp can handle such voltages) since V_{REF} is permitted to exceed V_{DD} . Table II shows the code relationship for the circuit of Figure 4.

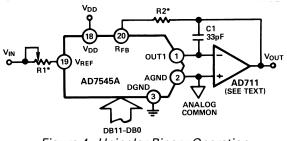


Figure 4. Unipolar Binary Operation

Table I. Recommended Trim Resistor Values vs. Grades

| Trim Resistor | K/B/T | L/C/U |
|---------------|-------------|-------|
| R1 | 200 Ω | 100 Ω |
| R2 | 68Ω | 33 Ω |

Table II. Unipolar Binary Code Table for Circuit of Figure 4

| Binary I DAC Re | Number in egister | | Analog Output |
|--------------------|----------------------|------|---|
| 1111 | 1111 | 1111 | $-V_{IN}\left(\frac{4095}{4096}\right)$ |
| 1000 | 0000 | 0000 | $-V_{IN}\left(\frac{2048}{4096}\right) = -1/2 V_{IN}$ |
| 0000 | 0000 | 0001 | $-V_{IN}\left(\frac{1}{4096}\right)$ |
| 0000 | 0000 | 0000 | 0 Volts |

Figure 5 and Table III illustrate the recommended circuit and code relationship for bipolar operation. The D/A function itself uses offset binary code and inverter U_1 on the MSB line converts twos complement input code to offset binary code. If appropriate, inversion of the MSB may be done in software using an exclusive –OR instruction and the inverter omitted. R3, R4 and R5 must be selected to match within 0.01%, and they should be the same type of resistor (preferably wire-wound or metal foil), so that their temperature coefficients match. Mismatch of R3 value to R4 causes both offset and full-scale error.

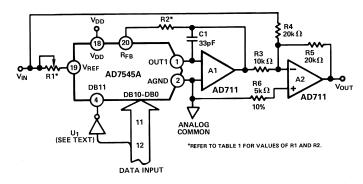


Figure 5. Bipolar Operation (Twos Complement Code)

Table III. Twos Complement Code Table for Circuit ofFigure 5

| Γ | Data Input | | Analog Output |
|------|------------|------|---|
| 0111 | 1111 | 1111 | $+V_{IN} \times \left(\frac{2047}{2048}\right)$ |
| 0000 | 0000 | 0001 | $+V_{IN} \times \left(\frac{1}{2048}\right)$ |
| 0000 | 0000 | 0000 | 0 Volts |
| 1111 | 1111 | 1111 | $-V_{IN} \times \left(\frac{1}{2048}\right)$ |
| 1000 | 0000 | 0000 | $-V_{IN} \times \left(\frac{2048}{2048}\right)$ |

Figure 6 and Table IV show an alternative method of achieving bipolar output. The circuit operates with sign plus magnitude code and has the advantage that it gives 12-bit resolution in each quadrant compared with 11-bit resolution per quadrant for the circuit of Figure 5. The AD7592 is a fully protected CMOS change-over switch with data latches. R4 and R5 should match each other to 0.01% to maintain the accuracy of the D/A converter. Mismatch between R4 and R5 introduces a gain error. Refer to Reference 1 (supplemental application material) for additional information on these circuits.

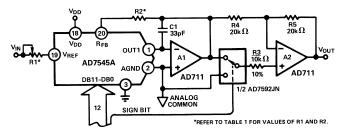


Figure 6. 12-Bit Plus Sign Magnitude Converter

| Table IV. | 12-Bit Plus | Sign Mag | nitude Code | Table for Circuit |
|-----------|-------------|----------|-------------|--------------------------|
| of Figure | 6 | | | |

| Sign Bit | Binary Numbers in DAC Register | Analog Output | |
|-------------|-----------------------------------|--|--|
| 0 | 1111 1111 1111 | + $V_{IN} \times \left(\frac{4095}{4096}\right)$ | |
| 0 | 0000 0000 0000 | 0 Volts | |
| 1 | 0000 0000 0000 | 0 Volts | |
| 1 | 1111 1111 1111 | $-V_{IN} \times \left(\frac{4095}{4096}\right)$ | |

Note: Sign bit of "0" connects R3 to GND.

APPLICATIONS HINTS

Output Offset: CMOS D/A converters such as Figures 4, 5 and 6 exhibit a code dependent output resistance which, in turn, can cause a code dependent error voltage at the output of the amplifier. The maximum amplitude of this error, which adds to the D/A converter nonlinearity, depends on V_{OS} , where V_{OS} is the amplifier input offset voltage. To maintain specified accuracy with V_{REF} at 10 V, it is recommended that V_{OS} be no greater than 0.25 mV, or (25×10^{-6}) (V_{REF}), over the temperature range of operation. Suitable op amps are AD517 and AD711. The AD517 is best suited for fixed reference applications with low bandwidth requirements: it has extremely low offset (150 µV max for lowest grade) and in most applications will not require an offset trim. The AD711 has a much wider bandwidth and higher slew rate and is recommended for multiplying and other applications requiring fast settling. An offset trim on the AD711 may be necessary in some circuits.

General Ground Management: AC or transient voltages between AGND and DGND can cause noise injection into the analog output. The simplest method of ensuring that voltages at AGND and DGND are equal is to tie AGND and DGND together at the AD7545A. In more complex systems where the AGND and DGND intertie is on the backplane, it is recommended that two diodes be connected in inverse parallel between the AD7545A AGND and DGND pins (1N914 or equivalent).

Invalid Data: When \overline{WR} and \overline{CS} are both low, the latches are transparent and the D/A converter inputs follow the data inputs. In some bus systems, data on the data bus is not always valid for the whole period during which \overline{WR} is low, and as a result invalid data can briefly occur at the D/A converter inputs during a write cycle. Such invalid data can cause unwanted signals or glitches at the output of the D/A converter. The solution to this problem, if it occurs, is to retime the write pulse, \overline{WR} , so it only occurs when data is valid.

Digital Glitches: Digital glitches result due to capacitive coupling from the digital lines to the OUT1 and AGND terminals. This should be minimized by screening the analog pins of the AD7545A (Pins 1, 2, 19, 20) from the digital pins by a ground track run between Pins 2 and 3 and between Pins 18 and 19 of the AD7545A.

Note how the analog pins are at one end (DIP) or side (LCC and PLCC) of the package and separated from the digital pins by V_{DD} and DGND to aid screening at the board level. On-chip capacitive coupling can also give rise to crosstalk from the digital-to-analog sections of the AD7545A, particularly in circuits with high currents and fast rise and fall times. This type of crosstalk is minimized by using V_{DD} = +5 volts. However, great care should be taken to ensure that the +5 V used to power the AD7545A is free from digitally induced noise.

Temperature Coefficients: The gain temperature coefficient of the AD7545A has a maximum value of 5 ppm/°C and a typical value of 2 ppm/°C. This corresponds to worst case gain shifts of 2 LSBs and 0.8 LSBs respectively over a 100°C temperature range. When trim resistors R1 and R2 (such as in Figure 4) are used to adjust full-scale range, the temperature coefficient of R1 and R2 should also be taken into account. The reader is referred to Analog Devices Application Note "Gain Error and Gain Temperature Coefficient to CMOS Multiplying DACs," Publication Number E630c–5–3/86.

SINGLE SUPPLY OPERATION

The ladder termination resistor of the AD7545A (Figure 1) is connected to AGND. This arrangement is particularly suitable for single supply operation because OUT1 and AGND may be biased at any voltage between DGND and V_{DD} . OUT1 and AGND should never go more than 0.3 volts less than DGND or an internal diode will be turned on and a heavy current may flow that will damage the device. (The AD7545A is, however, protected from the SCR latchup phenomenon prevalent in many CMOS devices.)

Figure 7 shows the AD7545A connected in a voltage switching mode. OUT1 is connected to the reference voltage and AGND is connected to DGND. The D/A converter output voltage is available at the V_{REF} pin and has a constant output impedance equal to R. R_{FB} is not used in this circuit and should be tied to OUT1 to minimize stray capacitance effects.

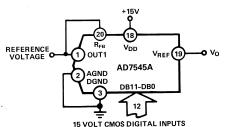


Figure 7. Single Supply Operation Using Voltage Switching Mode

The loading on the reference voltage source is code-dependent and the response time of the circuit is often determined by the behavior of the reference voltage with changing load conditions. To maintain linearity, the voltages at OUT1 and AGND should remain within 2.5 volts of each other, for a V_{DD} of 15 volts. If V_{DD} is reduced from 15 V, or the differential voltage between OUT1 and AGND is increased to more than 2.5 V, the differential nonlinearity of the DAC will increase and the linearity of the DAC will be degraded. Figures 8 and 9 show typical curves illustrating this effect for various values of reference voltage and V_{DD}. If the output voltage is required to be offset from ground by some value, then OUT1 and AGND may be biased up. The effect on linearity and differential nonlinearity will be the same as reducing V_{DD} by the amount of the offset.

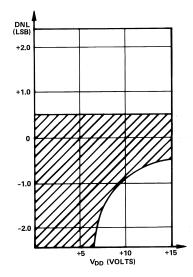


Figure 8. Differential Nonlinearity vs. V_{DD} for Figure 7 Circuit. Reference Voltage = 2.5 Volts. Shaded Area Shows Range of Values of Differential Nonlinearity that Typically Occur for all Grades.

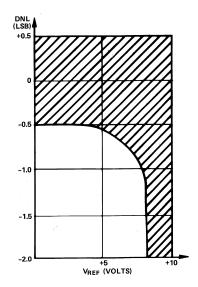


Figure 9. Differential Nonlinearity vs. Reference Voltage for Figure 7 Circuit. V_{DD} = 15 Volts. Shaded Area Shows Range of Values of Differential Nonlinearity that Typically Occur for all Grades.

The circuits of Figures 4, 5 and 6 can all be converted to single supply operation by biasing AGND to some voltage between V_{DD} and DGND. Figure 10 shows the 2s Complement Bipolar circuit of Figure 5 modified to give a range from +2 V to +8 V about a "pseudo-analog ground" of 5 V. This voltage range would allow operation from a single V_{DD} of +10 V to +15 V. The AD584 pin-programmable reference fixes AGND at +5 V. V_{IN} is set at +2 V by means of the series resistors R1 and R2.

There is no need to buffer the V_{REF} input to the AD7545A with an amplifier because the input impedance of the D/A converter is constant. Note, however, that since the temperature coefficient of the D/A reference input resistance is typically –300 ppm/°C, applications which experience wide temperature variations may require a buffer amplifier to generate the +2.0 V at the AD7545A V_{REF} pin. Other output voltage ranges can be obtained by changing R4 to shift the zero point and (R1 + R2) to change the slope, or gain of the D/A transfer function. V_{DD} must be kept at least 5 V above OUT1 to ensure that linearity is preserved.

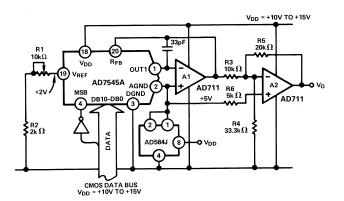


Figure 10. Single Supply "Bipolar" 2s Complement D/A Converter

MICROPROCESSOR INTERFACING OF THE AD7545A The AD7545A can interface directly to both 8- and 16-bit microprocessors via its 12-bit wide data latch using standard \overline{CS} and \overline{WR} control signals.

A typical interface circuit for an 8-bit processor is shown in Figure 11. This arrangement uses two memory addresses, one for the lower 8 bits of data to the DAC and one for the upper 4 bits of data into the DAC via the latch.

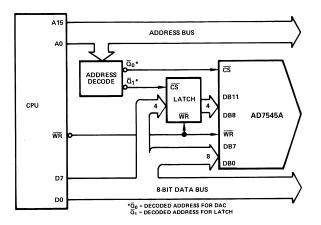


Figure 11. 8-Bit Processor to AD7545 Interface

Figure 12 shows an alternative approach for use with 8-bit processors which have a full 16-bit wide address bus such as 6800, 8080, Z80. This technique uses the 12 lower address lines of the processor address bus to supply data to the DAC, thus each AD7545A connected in this way uses 4k bytes of address locations. Data is written to the DAC using a single memory write instruction. The address field of the instruction is organized so that the lower 12 bits contain the data for the DAC and the upper 4 bits contain the address of the 4k block at which the DAC resides.

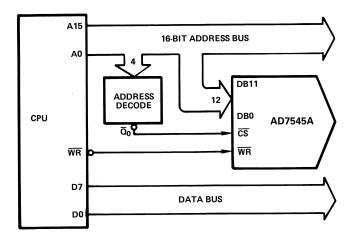


Figure 12. Connecting the AD7545A to 8-Bit Processors via the Address Bus

SUPPLEMENTAL APPLICATION MATERIAL

For further information on CMOS multiplying D/A converters the reader is referred to the following texts:

Reference 1

CMOS DAC Application Guide available from Analog Devices, Publication Number G872a-15-4/86.

Reference 2

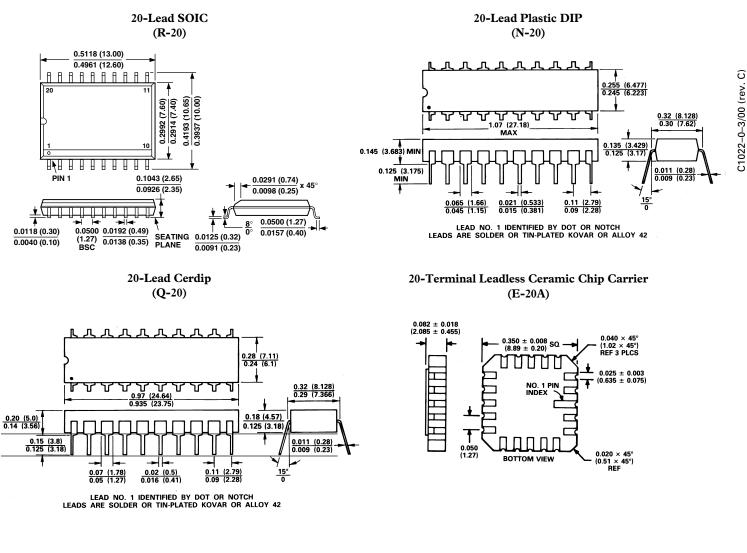
Gain Error and Gain Temperature Coefficient of CMOS Multiplying DACs – Application Note, Publication Number E630c-5-3/86.

Reference 3

Analog-Digital Conversion Handbook (Third Edition) available from Prentice-Hall.

OUTLINE DIMENSIONS

Dimensions shown in inches and (mm).



20-Terminal Plastic Leadless Chip Carrier (P-20A)

